onsemi

<u>Silicon Carbide (SiC)</u> <u>Schottky Diode</u> – EliteSiC, 25 A, 1700 V, D1, TO-247-2L

NDSH25170A

Description

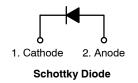
Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 506 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- These Devices are Halogen Free/BFR Free and are RoHS Compliant

Applications

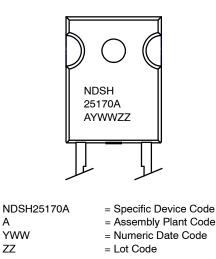
- SMPS, Solar Inverter, UPS
- Power Switching Circuits





CASE 340DA

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

NDSH25170A

Symbol	Parameter	Value	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage		1700	V
E _{AS}	Single Pulse Avalanche Energy (Note 1)	Single Pulse Avalanche Energy (Note 1)		mJ
١ _F	Continuous Rectified Forward Current @ T _C < 153°C		25	А
	Continuous Rectified Forward Current @ T_C < \sim	35		
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	T _C = 25°C, 10 μs	1435	А
		T _C = 150°C, 10 μs	1428	А
I _{F,SM}	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	220	А
I _{F,RM}	F,RM Repetitive Forward Surge Current Half-Sine Pu		66	А
Ptot	Power Dissipation	$T_{\rm C} = 25^{\circ}{\rm C}$	385	W
		T _C = 150°C	64	W
T _J , T _{STG}	Operating and Storage Temperature Range		–55 to +175	°C

ABSOLUTE MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. E_{AS} of 506 mJ is based on starting $T_J = 25^{\circ}C$, L = 0.5 mH, $I_{AS} = 45$ A, V = 50 V.

THERMAL CHARACTERISTICS

Symbol	Symbol Parameter		Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max	0.39	°C/W

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V _F	Forward Voltage	I _F = 25 A, T _J = 25°C	-	1.50	1.75	V
		I _F = 25 A, T _J = 125°C	-	1.95	2.35	
		I _F = 25 A, T _J = 175°C	-	2.32	2.8	
I _R	Reverse Current	V _R = 1700 V, T _J = 25°C	-	0.08	40	μΑ
		$V_{R} = 1700 \text{ V}, \text{ T}_{J} = 125^{\circ}\text{C}$	-	0.58	60	
		V _R = 1700 V, T _J = 175°C	-	4.24	100	
Q_{C}	Total Capacitive Charge	V = 800 V	-	169	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	2025	-	pF
		V _R = 400 V, f = 100 kHz	-	155	-	
		V _R = 800 V, f = 100 kHz	-	109	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Part Number	Top Marking	Package	Shipping
NDSH25170A	NDSH25170A	TO-247-2LD (Pb-Free / Halogen Free)	30 Units / Tube

NDSH25170A

TYPICAL CHARACTERISTICS

(T_J = 25°C UNLESS OTHERWISE NOTED)

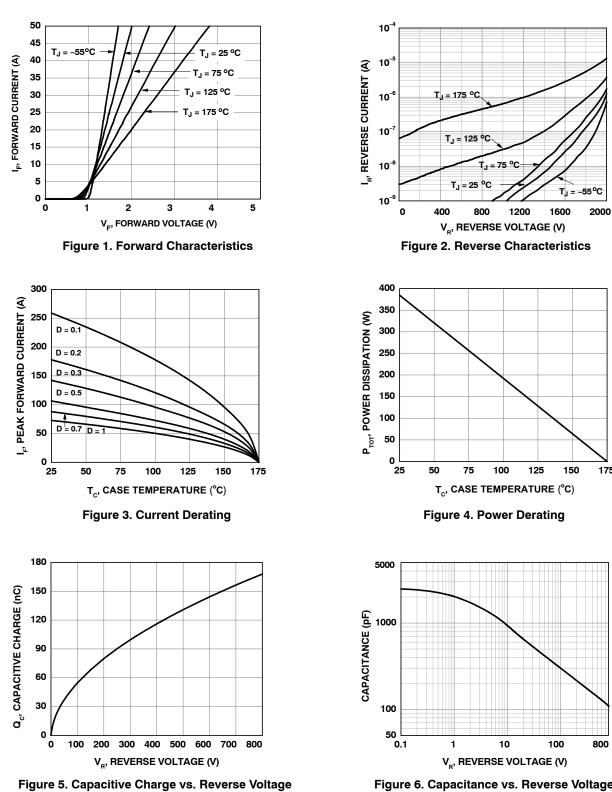


Figure 6. Capacitance vs. Reverse Voltage

175

800

NDSH25170A

TYPICAL CHARACTERISTICS

 $(T_J = 25^{\circ}C \text{ UNLESS OTHERWISE NOTED})$

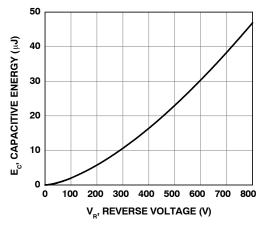


Figure 7. Capacitance Stored Energy

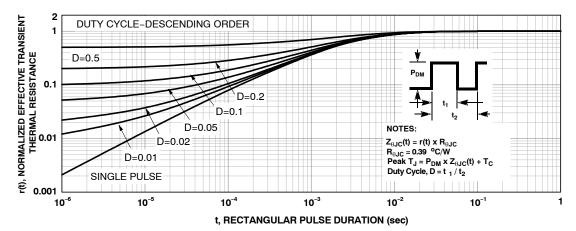
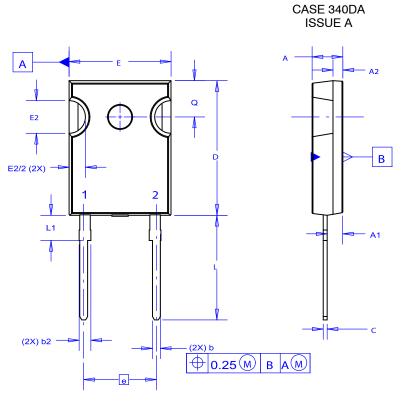


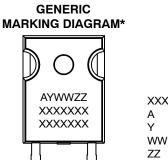
Figure 8. Junction-to-Case Transient Thermal Response Curve





NOTES: UNLESS OTHERWISE SPECIFIED.

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD
- FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.



XXXXX = Specific Device Code A = Assembly Location Y = Year

TO-247-2LD

V = Work Week

= Assembly Lot Code

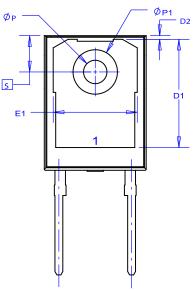
*This information is generic. Please refer to device data sheet for actual part marking. Pb– Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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 DESCRIPTION:
 TO-247-2LD
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	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	4.58	4.70	4.82	
A1	2.20	2.40	2.60	
A2	1.40	1.50	1.60	
b	1.17	1.26	1.35	
b2	1.53	1.65	1.77	
с	0.51	0.61	0.71	
D	20.32	20.57	20.82	
D1	13.08	~	~	
D2	0.51	0.93	1.35	
E	15.37	15.62	15.87	
E1	12.81	~	~	
E2	4.96	5.08	5.20	
е	~	11.12	~	
L	15.75	16.00	16.25	
L1	3.69	3.81	3.93	
ØР	3.51	3.58	3.65	
Ø P1	6.60	6.80	7.00	
Q	5.34	5.46	5.58	
S	5.34	5.46	5.58	

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